EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L13	19	(electronic adj circuit) same (substrate with ("tft" or ((film or thin$1film) near2 transistor))) same optic$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L14	24	("tft" or ((film or thin$1film) near2 transistor)) same crystal$5 same (heat$3 near2 treat$4) same (irradiat$3 or laser) same (metal near2 catalyst)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L15	9	("tft" or ((film or thin$1film) near2 transistor)) same crystal$5 same (heat$3 near2 treat$4) same (irradiat$3 or laser) same (benefit or advantage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L16	239	("tft" or ((film or thin$1film) near2 transistor)) same ((semi$1conduct$3 or semiconduct$3) near2 different near2 layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L17	35	("tft" or ((film or thin$1film) near2 transistor)) same ((semi$1conduct$3 or semiconduct$3) near2 (different adj layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L18	9	("tft" or ((film or thin$1film) near2 transistor)) same ((semi$1conduct$3 or semiconduct$3) near2 (different adj material))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L19	46	(amorphous near2 (photodiode or photo$1diode or phototransistor or photo$1transistor)) same (semiconduct$3 near2 (layer or material))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06

L20	4973	(((shutter or block$3) with (transmission or transmit $4) with (signal or light)) same (liquid adj crystal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L21	475188	"257"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L22	182	L20 and L21	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L23	130	L22 and ((stack or layer or substrate) same ("tft" or "transistor"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L24	979	((photodiode or photosens $3) same ("tft" or transistor) same buffer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L25	75409	"385"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L26	8	L24 and L25	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L27	475188	"257"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06

L28	383	L24 and L27	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L29	160	(L13 L14 L15 L16 L17 L18 L19 L23 L26 L28) and @pd>"20081001"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:06
L32	5966	385/14.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:21
L33	3	l32 and (("tft" or ((film or thin$1film) near2 transistor)) same ((stack $3 or layer) near2 substrate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:22
L34	17	l32 and (("tft" or ((film or thin$1film) near2 transistor)) same (stack$3 or layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:22
L35	16	l34 not (L13 L14 L15 L16 L17 L18 L19 L23 L26 L28)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:24
L36	44	l32 and ("tft" or ((film or thin$1film) near2 transistor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:24
L37	27	l36 not (L13 L14 L15 L16 L17 L18 L19 L23 L26 L28 l34)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:24

L38	26	I25 and (("tft" or ((film or thin$1film) near2 transistor)) same ((stack $3 or layer) near2 substrate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:25
L39	23	I38 not (L13 L14 L15 L16 L17 L18 L19 L23 L26 L28 I34 I36)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:25
L40	185	I25 and (("tft" or ((film or thin$1film) near2 transistor)) same (stack$3 or layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:26
L41	145	I40 not (L13 L14 L15 L16 L17 L18 L19 L23 L26 L28 I34 I36 I38)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:26
L42	8	I25 and ("tft" or ((film or thin$1film) near2 transistor)) and (parallel near2 process$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:27
L43	2	I42 not (L13 L14 L15 L16 L17 L18 L19 L23 L26 L28 I34 I36 I38 I40)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:28
L45	6223	I27 and (("tft" or ((film or thin$1film) near2 transistor)) same ((stack $3 or layer) near2 substrate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:29
L46	60	I27 and (("tft" or ((film or thin$1film) near2 transistor)) same ((stack $3 or layer) near2 substrate)) and (parallel near2 process$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:31

L47	59	I46 not (L13 L14 L15 L16 L17 L18 L19 L23 L26 L28 I34 I36 I38 I40 I42)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:31
L48	28916	"398"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:34
L49	1	I48 and (("tft" or ((film or thin$1film) near2 transistor)) same ((stack $3 or layer) near2 substrate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:34
L50	0	I48 and ("tft" or ((film or thin$1film) near2 transistor)) and (parallel near2 process$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:35
L51	439	I25 and ("tft" or ((film or thin$1film) near2 transistor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:36
L52	225	I51 not (L13 L14 L15 L16 L17 L18 L19 L23 L26 L28 I34 I36 I38 I40 I42 I46)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:36
L53	44	I48 and ("tft" or ((film or thin$1film) near2 transistor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:37
L54	42	I53 not (L13 L14 L15 L16 L17 L18 L19 L23 L26 L28 I34 I36 I38 I40 I42 I46 I51)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:37

L55	0	(("tft" or ((film or thin $1film) near2 transistor)) and shutter and laminat$3 and sensor and buffer). clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/25 19:48

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